



SANYO Semiconductors

# DATA SHEET

An ON Semiconductor Company

## CPH3109 / CPH3209 — DC / DC Converter Applications

PNP / NPN Epitaxial Planar Silicon Transistors

### Applications

- Relay drivers, lamp drivers, motor drivers, strobes

### Features

- Adoption of MBIT processes
- Large current capacity
- Low collector-to-emitter saturation voltage
- High-speed switching
- Ultrasmall package facilitates miniaturization in end products (mounting height : 0.9mm)
- High allowable power dissipation

### Specifications ( ) : CPH3109

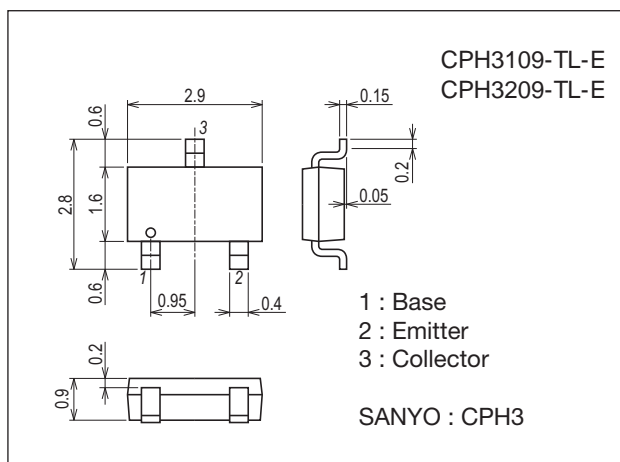
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(-30)40	V
Collector-to-Emitter Voltage	VCEO		(-)30	V
Emitter-to-Base Voltage	VEBO		(-)5	V
Collector Current	IC		(-)3	A
Collector Current (Pulse)	ICP		(-)5	A
Base Current	IB		(-)600	mA
Collector Dissipation	PC	When mounted on ceramic substrate (600mm <sup>2</sup> ×0.8mm)	0.9	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### Package Dimensions

unit : mm (typ)

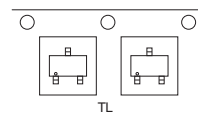
7015A-003



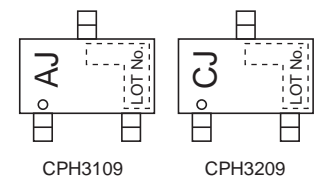
### Product & Package Information

- Package : CPH3
- JEITA, JEDEC : SC-59, TO-236, SOT-23
- Minimum Packing Quantity : 3,000 pcs./reel

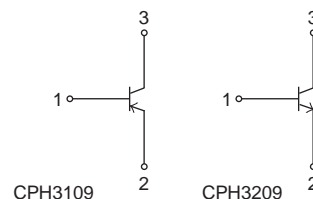
### Packing Type: TL



### Marking



### Electrical Connection

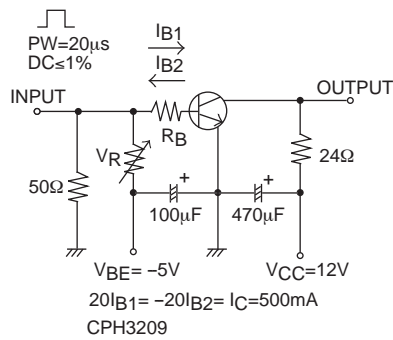
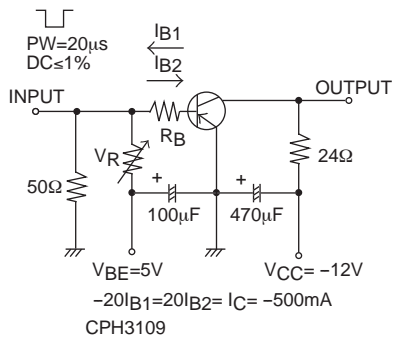


# CPH3109 / CPH3209

## Electrical Characteristics at Ta=25°C

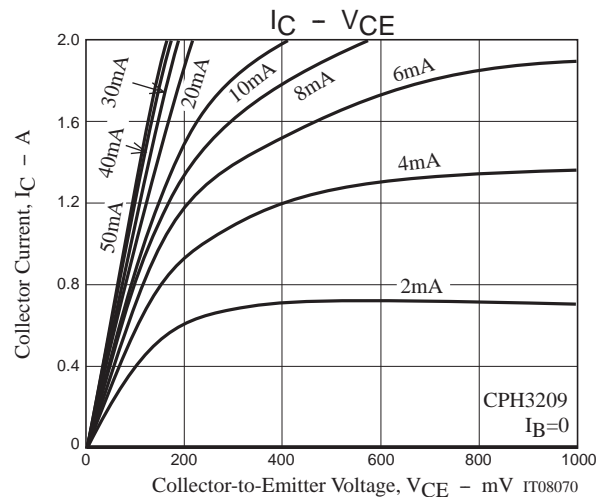
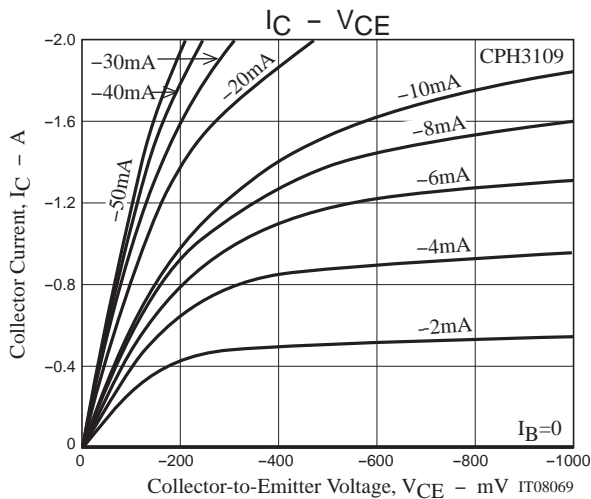
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = (-)30V, I_E = 0A$			(-)0.1	$\mu A$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = (-)4V, I_C = 0A$			(-)0.1	$\mu A$
DC Current Gain	$h_{FE}$	$V_{CE} = (-)2V, I_C = (-)500mA$	200		560	
Gain-Bandwidth Product	$f_T$	$V_{CE} = (-)10V, I_C = (-)500mA$		(380)450		MHz
Output Capacitance	$C_{ob}$	$V_{CB} = (-)10V, f = 1MHz$		(25)20		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)1}$	$I_C = (-)1.5A, I_B = (-)30mA$		(-155)120	(-230)180	mV
	$V_{CE(sat)2}$	$I_C = (-)1.5A, I_B = (-)75mA$		(-)105	(-)155	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = (-)1.5A, I_B = (-)30mA$		(-)0.83	(-)1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)10\mu A, I_E = 0A$	(-30)40			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = (-)1mA, R_{BE} = \infty$	(-)30			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = (-)10\mu A, I_C = 0A$	(-)5			V
Turn-On Time	$t_{on}$	See specified Test Circuit.		(50)30		ns
Storage Time	$t_{stg}$			(270)300		ns
Fall Time	$t_f$			(25)15		ns

## Switching Time Test Circuit

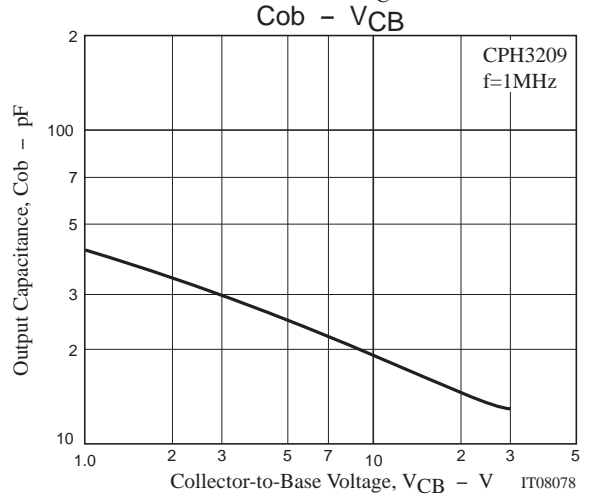
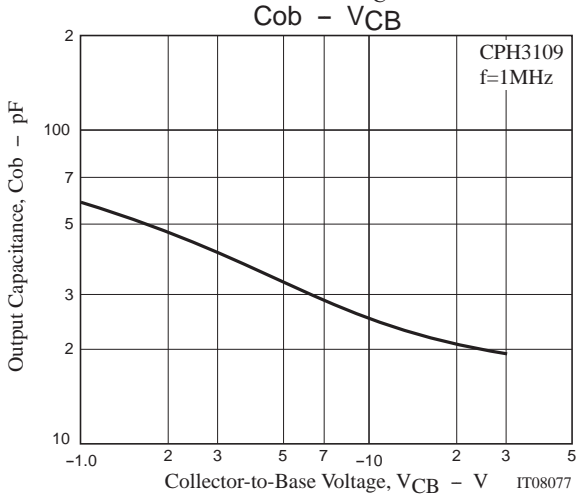
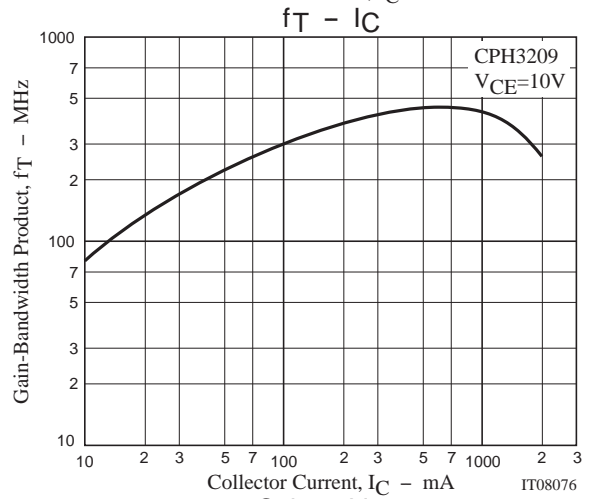
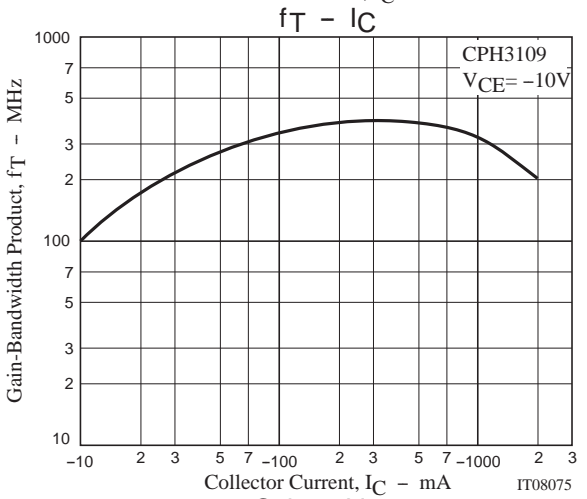
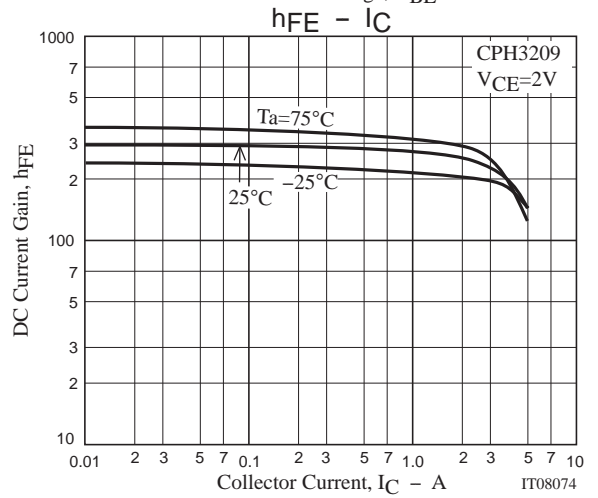
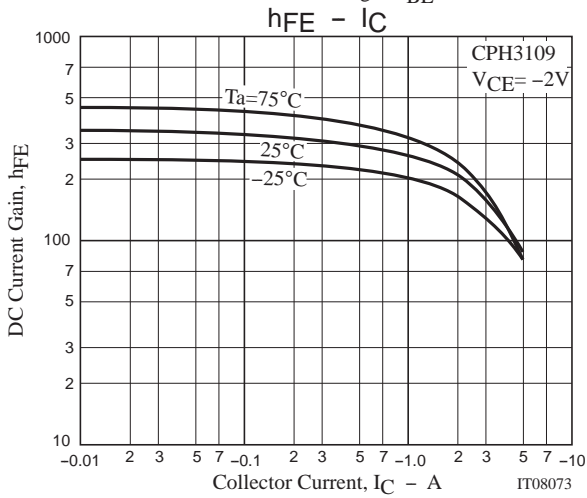
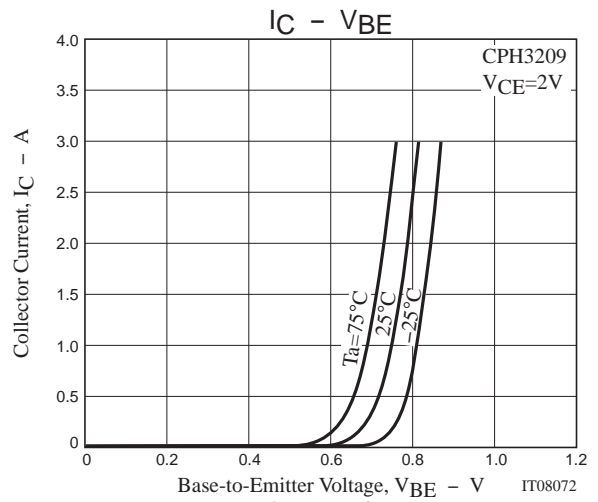
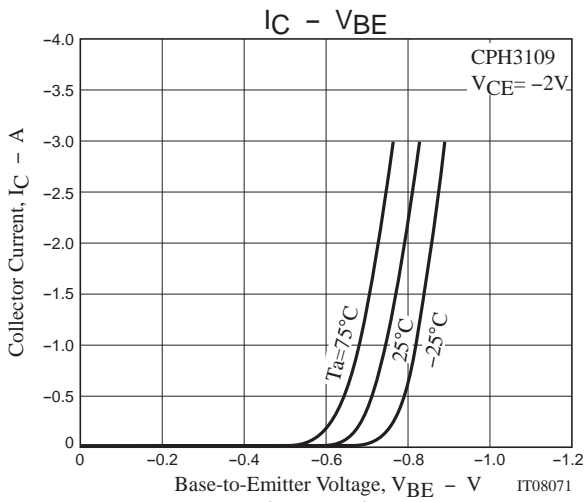


## Ordering Information

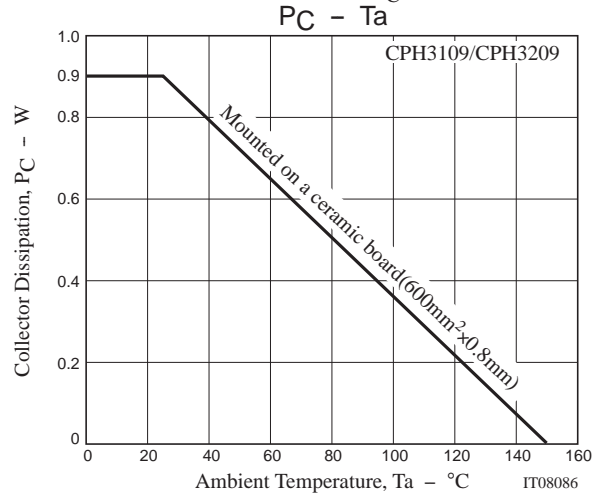
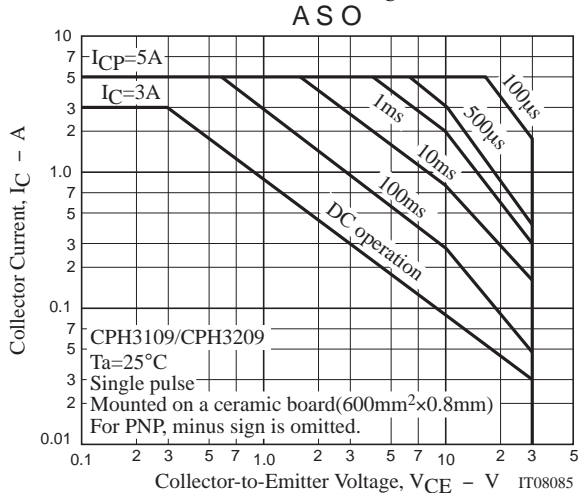
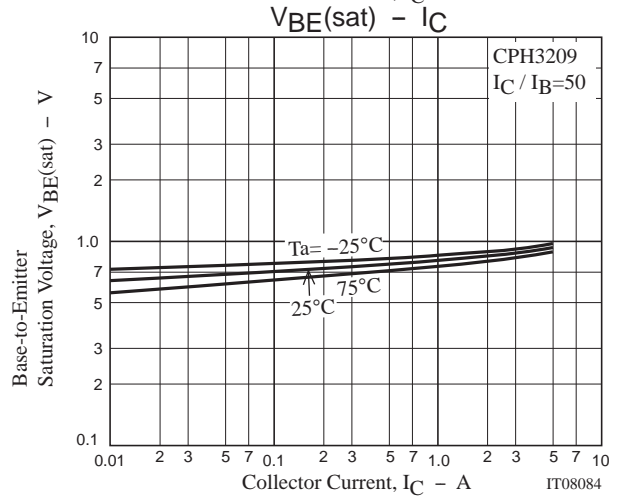
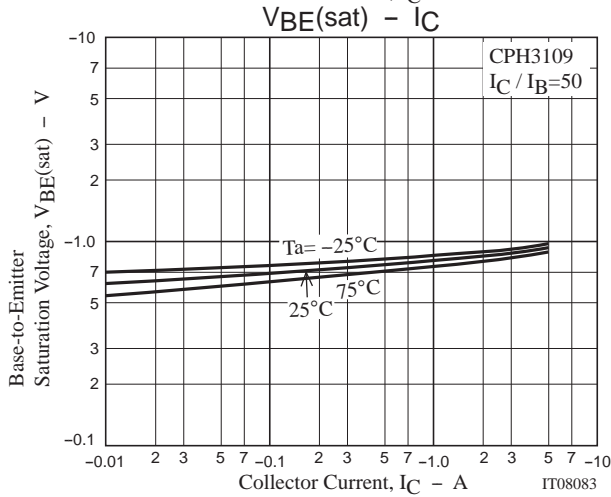
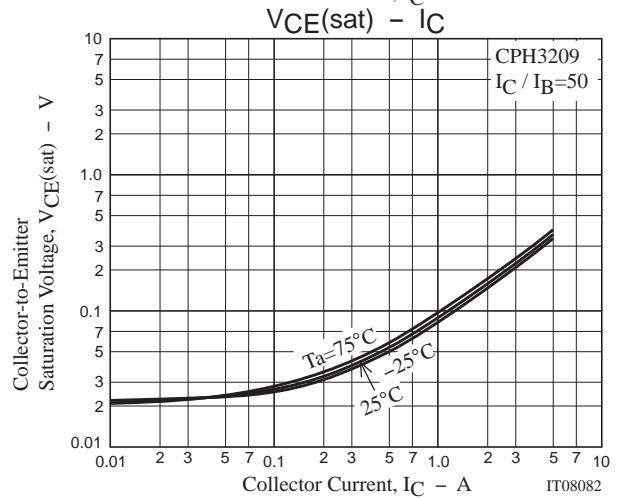
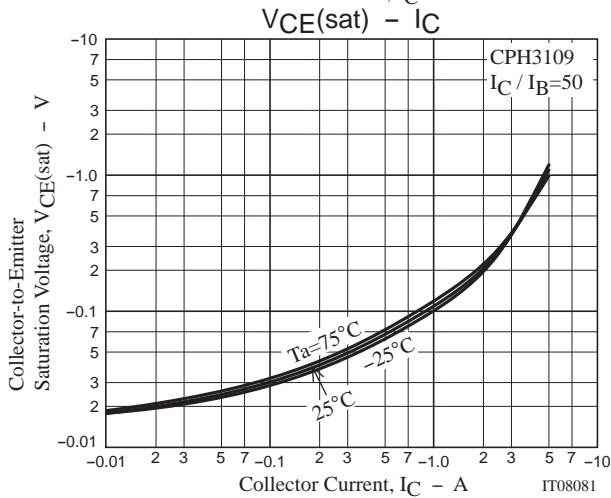
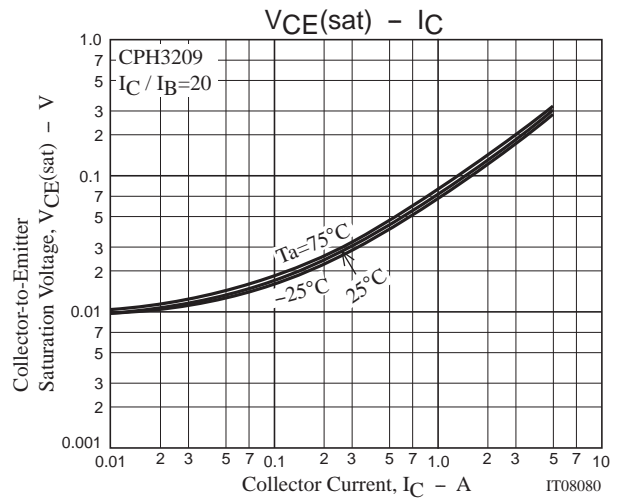
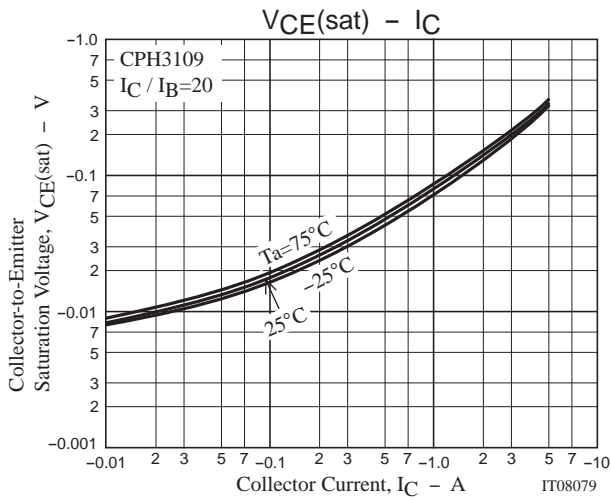
Device	Package	Shipping	memo
CPH3109-TL-E	CPH3	3,000pcs./reel	Pb Free
CPH3209-TL-E	CPH3	3,000pcs./reel	Pb Free



CPH3109 / CPH3209



# CPH3109 / CPH3209



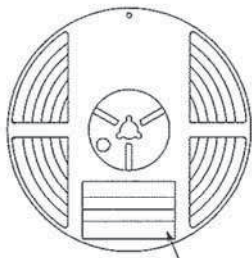
Embossed Taping Specification

CPH3109-TL-E, CPH3209-TL-E

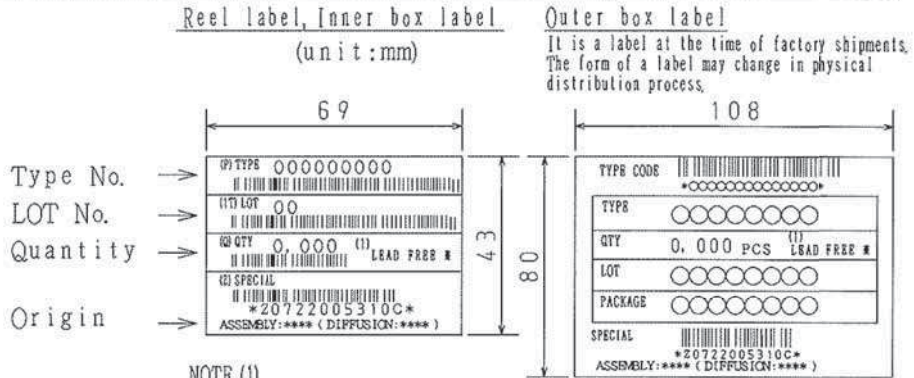
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CPH3	CPH3	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method



Reel label



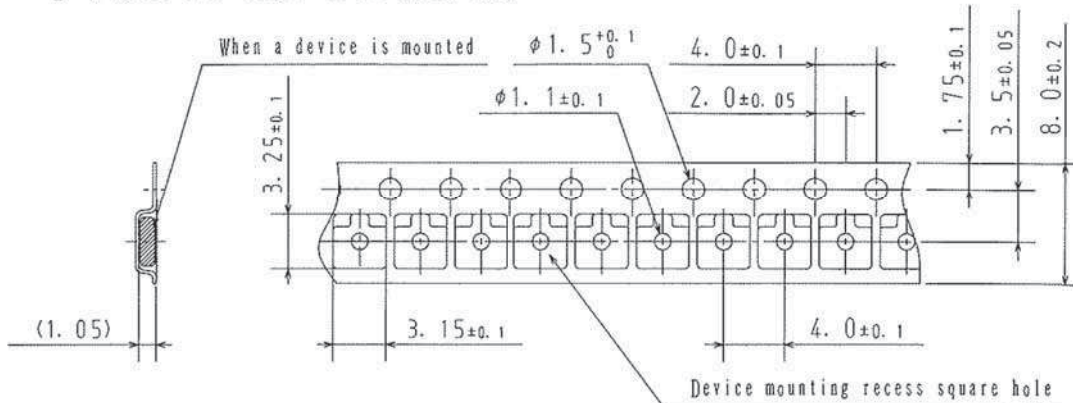
NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

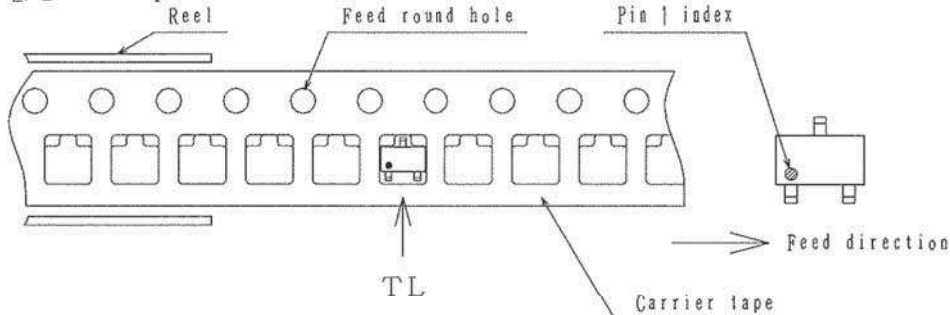
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

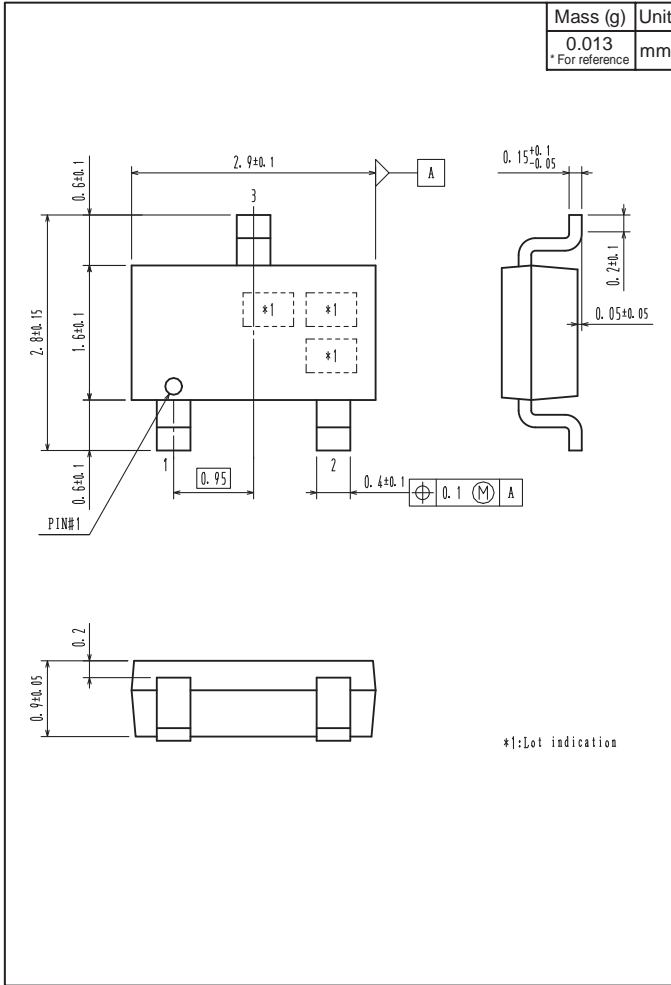


Those with one electrode terminal on the feed hole side.....TL

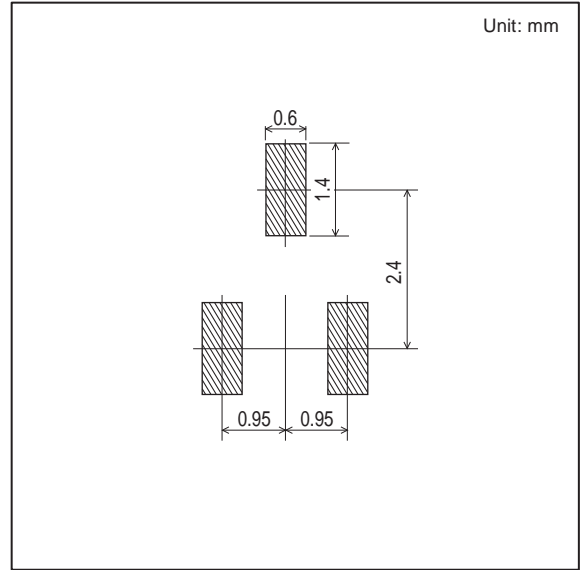
# CPH3109 / CPH3209

## Outline Drawing

CPH3109-TL-E, CPH3209-TL-E



## Land Pattern Example



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